NSN 5961-00-927-5928



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-927-5928 **Inclosure Material:** Metal **Overall Length:** Between 0.140 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Function For Which Designed:** Amplifier **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.190 inches and 0.210 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 80.0 collector to emitter reverse voltage all transistor and 7.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector preset all transistor

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Test Data Document:

10001-2548594 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0